NSN 5961-00-784-7576

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View Online at https://aerobasegroup.com/nsn/5961-00-784-7576 **Inclosure Material:** Metal **Overall Length:** 0.832 inches **Overall Height:** 0.260 inches **Overall Width:** 0.390 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, collector-to-base, emitter open and 1.5 emitter to base voltage, static, collector open and 100.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector **Transfer Ratio:** 15.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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